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Product: Ultrafast Recovery Rectifiers

FAGOR ELECTRONICA's Ultrafast Recovery Rectifiers offer reverse recovery times down to 30ns using broad range of forward current possibilities and packages.

Ideal for high frequency applications like SMPS, Monitors, Electronic Ballast, Inverters....

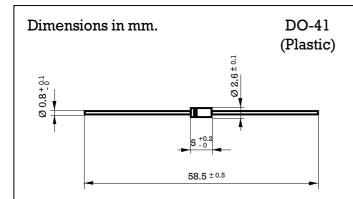
 $\label{thm:manufactured} \mbox{ Manufactured using HYPERECTIFIER} @ \mbox{ technology, we offer these devices housed either in leaded packages or SMD.}$

Product	Family	$I_{F(AV)}(A)$	$I_{FSM}(A)$	$V_{RRM}(V)$	$V_F(V)$	T _{RR} (ns)	OUTLINE
FUF4007	FUF4000	1.0	30	1000	1.7	75	DO-41





1 Amp. Glass Passivated Ultrafast Recovery Rectifier



Voltage Current 50 to 1000 V. 1 A at 55 °C.

Mounting instructions

- 1. Min. distance from body to soldering point, 4 mm.
- 2. Max. solder temperature, 350 °C.
- 3. Max. soldering time, 3.5 sec.
- 4. Do not bend lead at a point closer than 2 mm. to the body.

• Glass Passivated Junction

- High current capability
- The plastic material carries U/L recognition 94 V-0
- Terminals: Axial Leads
- Polarity: Color band denotes cathode

Maximum Ratings, according to IEC publication No. 134

		FUF 4001	FUF 4002	FUF 4003	FUF 4004	FUF 4005	FUF 4006	FUF 4007
V_{RRM}	Peak Recurrent reverse voltage (V)	50	100	200	400	600	800	1000
V _{RMS}	Maximum RMS voltage	35	70	140	280	420	560	700
V _{DC}	Maximum DC blocking voltage	50	100	200	400	600	800	1000
$I_{F(AV)}$	Forward current at Tamb = 55 °C	1 A						
I_{FRM}	Recurrent peak forward surge current	10 A						
I_{FSM}	8.3 ms. peak forward surge current (Jedec Method)	30 A						
t _{rr}	Max. reverse recovery time from $I_{\scriptscriptstyle F}\!=0.5\text{A}$; $I_{\scriptscriptstyle R}\!=1\text{A}$; $I_{\scriptscriptstyle RR}\!=0.25\text{A}$	50 ns 75 ns						
C_{j}	Typical Junction Capacitance at 1 MHz and reverse voltaje of $4V_{\tiny DC}$	15 pF						
T_{j}	Operating temperature range	−65 to + 150 °C						
$T_{ m stg}$	Storage temperature range	− 65 to + 150 °C						
$E_{ ext{RSM}}$	Maximum non repetitive peak reverse avalanche energy. $I_R = 0.5A$; $T_J = 25$ °C	20 mJ						

Electrical Characteristics at Tamb = 25 °C

$V_{\scriptscriptstyle F}$	Max. forward voltage drop at $I_F = 1$ A	1.3 V	1.7 V		
I_R	Max. reverse current at $V_{\mbox{\tiny RRM}}$ at 25 °C	5 µ A			
R_{thj-a}	Max. thermal resistance ($l = 10 \text{ mm.}$)	50 °C/W			